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Prospects of THz Pulse Generation with mJ-Level Energy and 100 MV/cm Electric Field

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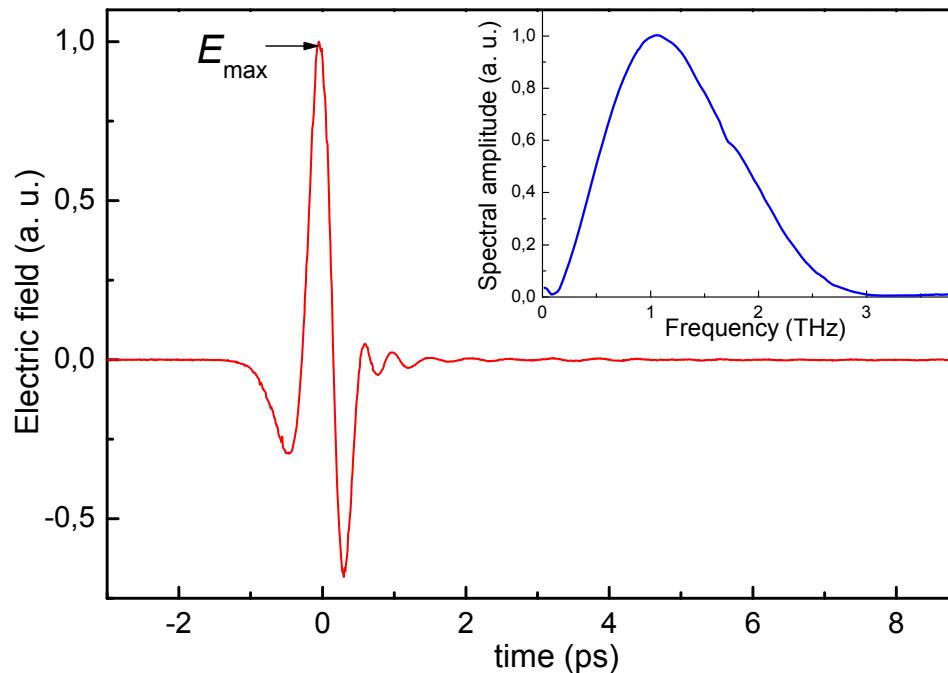
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Workshop on THz Sources for Time Resolved Studies of Matter, ANL, Argonne, July 30-31, 2012

Applications of High-Energy THz Pulses



- Linear THz spectroscopy ($E_{\max} \approx 100 \text{ V/cm} \rightarrow 10 \text{ fJ pulse energy}$)
graphene, nanotubes, molecular magnets, etc.
- Nonlinear THz spectroscopy ($E_{\max} \approx 100 \text{ kV/cm} \rightarrow \mu\text{J pulse energy}$)
THz pump – THz probe measurements of dynamics (Hoffmann et al., PRB, 2009)
- Manipulation and acceleration of charged particles
($E_{\max} \approx 100 \text{ MV/cm} \rightarrow 10 \text{ mJ pulse energy}$)
VUV–XUV pulse generation by Thomson-scattering, X-ray free electron laser, ...

Optical Rectification

Conversion efficiency depends on:

$$\eta_{\text{THz}} = \frac{2\omega_{\text{THz}}^2 d_{\text{eff}}^2 L^2 I}{\epsilon_0 n_v^2 n_{\text{THz}} c^3} \cdot e^{-\alpha_{\text{THz}} L/2} \cdot \frac{\sinh^2[\alpha_{\text{THz}} L/4]}{[\alpha_{\text{THz}} L/4]^2}$$

- THz frequency: $\eta_{\text{THz}} \propto \omega_{\text{THz}}^2$
- Material parameters → FOM
- Phase matching → velocity matching: $v_{\text{vis}}^{gr} = v_{\text{THz}}^{ph}$

Figure of merit (FOM):

$$\alpha_{\text{THz}} L \ll 1$$

$$\eta_{\text{THz}} = \frac{2\omega^2 d_{\text{eff}}^2 L^2 I}{\epsilon_0 n_v^2 n_{\text{THz}} c^3}$$

$$\alpha_{\text{THz}} L \gg 1$$

$$\eta_{\text{THz}} = \frac{8\omega^2 d_{\text{eff}}^2 I}{\epsilon_0 n_v^2 n_{\text{THz}} \alpha_{\text{THz}}^2 c^3}$$

$$FOM_{NA} = \frac{d_{\text{eff}}^2 L^2}{n_v^2 n_{\text{THz}}}$$

$$FOM_A = \frac{4d_{\text{eff}}^2}{n_v^2 n_{\text{THz}} \alpha_{\text{THz}}^2}$$

Materials for Optical Rectification

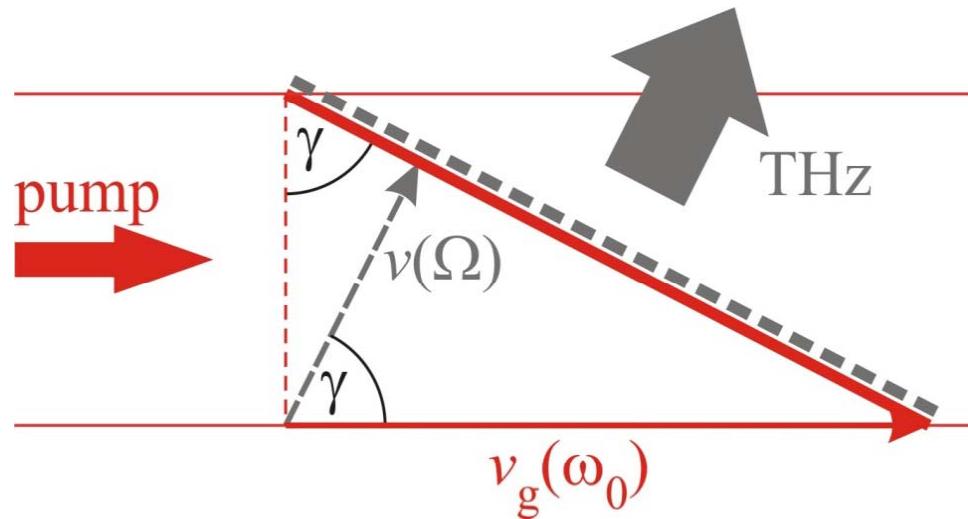
Material	d_{eff} (pm/V)	n_{800nm}^{gr}	n_{THz}	$n_{1.55\mu m}^{gr}$	α_{THz} (cm $^{-1}$)	FOM*
CdTe	81.8		3.24	2.81	4.8	11.0
GaAs	65.6	4.18	3.59	3.56	0.5	4.21
GaP	24.8	3.67	3.34	3.16	0.2	0.72
ZnTe	68.5	3.13	3.17	2.81	1.3	7.27
GaSe	28.0	3.13	3.27	2.82	0.5	1.18
sLiNbO ₃ sLN 100K	168	2.25	4.96	2.18	17 4.8	18.2 48.6
DAST	615	3.39	2.58	2.25	50	41.5

Velocity matching condition:

$$v_{NIR}^{gr} = v_{THz}^{ph} \Rightarrow n_{NIR}^{gr} = n_{THz}$$

* for $L = 2$ mm

Tilted-Pulse-Front Pumping (TPFP)



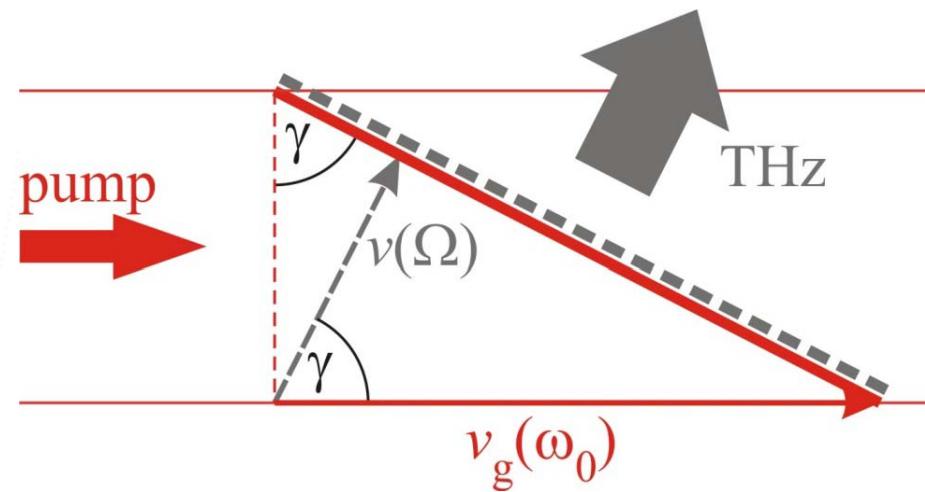
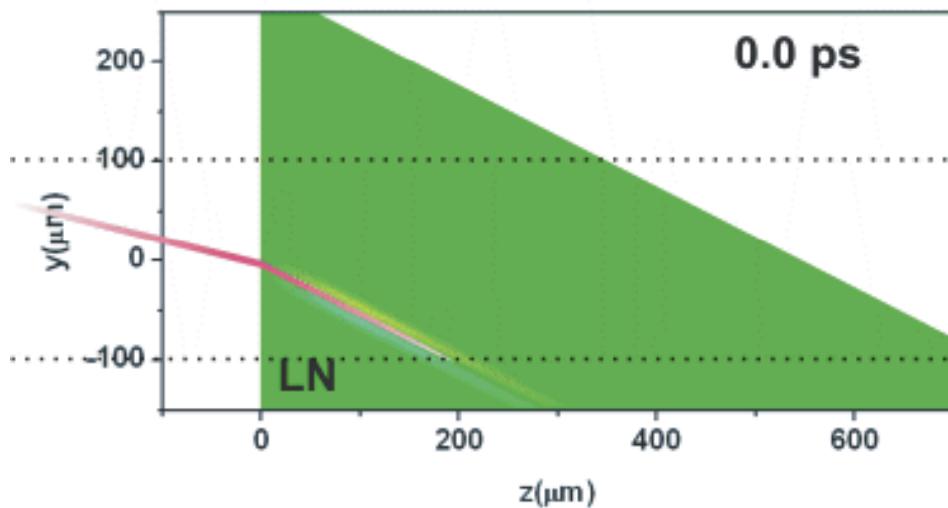
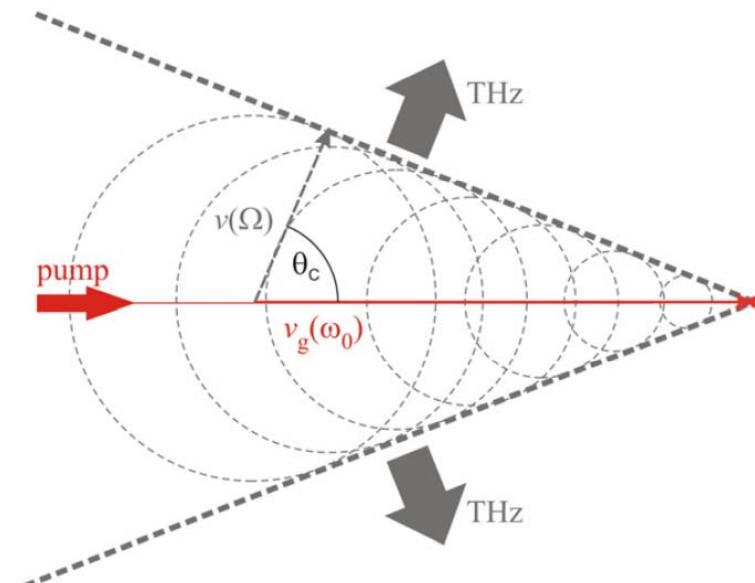
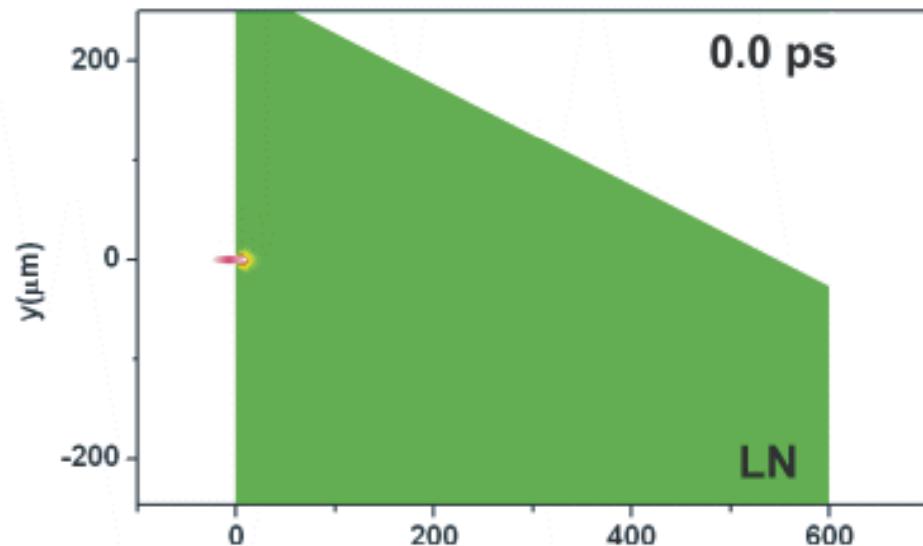
$$v_{\text{vis}}^{\text{gr}} \cdot \cos \gamma = v_{\text{THz}}^{\text{ph}}$$

Hebling et al.,
Opt. Express, 2002

~100 fs typical



Tilted-Pulse-Front Pumping vs. Line Focusing



Stepanov et al., Opt. Express, 2005

Hoffmann & Fülöp, J. Phys. D, 2011

THz Pulse Generation by Optical Rectification in LiNbO₃ Using Tilted Pulse Front Pumping

- Large nonlinear coefficient ($d_{\text{eff}} = 168 \text{ pm/V}$)
- Velocity matching by tilting the pump pulse front

$$v_{\text{vis}}^{\text{gr}} \cdot \cos \gamma = v_{\text{THz}}^{\text{ph}}$$

Hebling et al., Opt. Express, 2002

- Highest THz pulse energy from a table-top source

0.25 μJ

Stepanov et al., Opt. Express, 2005

10 μJ

Yeh et al., Appl. Phys. Lett., 2007

50 μJ

Stepanov et al., Appl. Phys. B, 2010

125 μJ

Fülöp et al., Opt. Lett., 2012

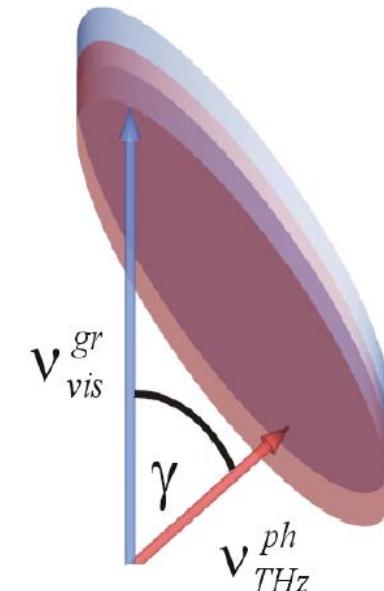
- Further increase of THz energy is in sight
 - optimal conditions
(pump pulse duration & wavelength, crystal temperature & length)

Fülöp et al., Opt. Express, 2011

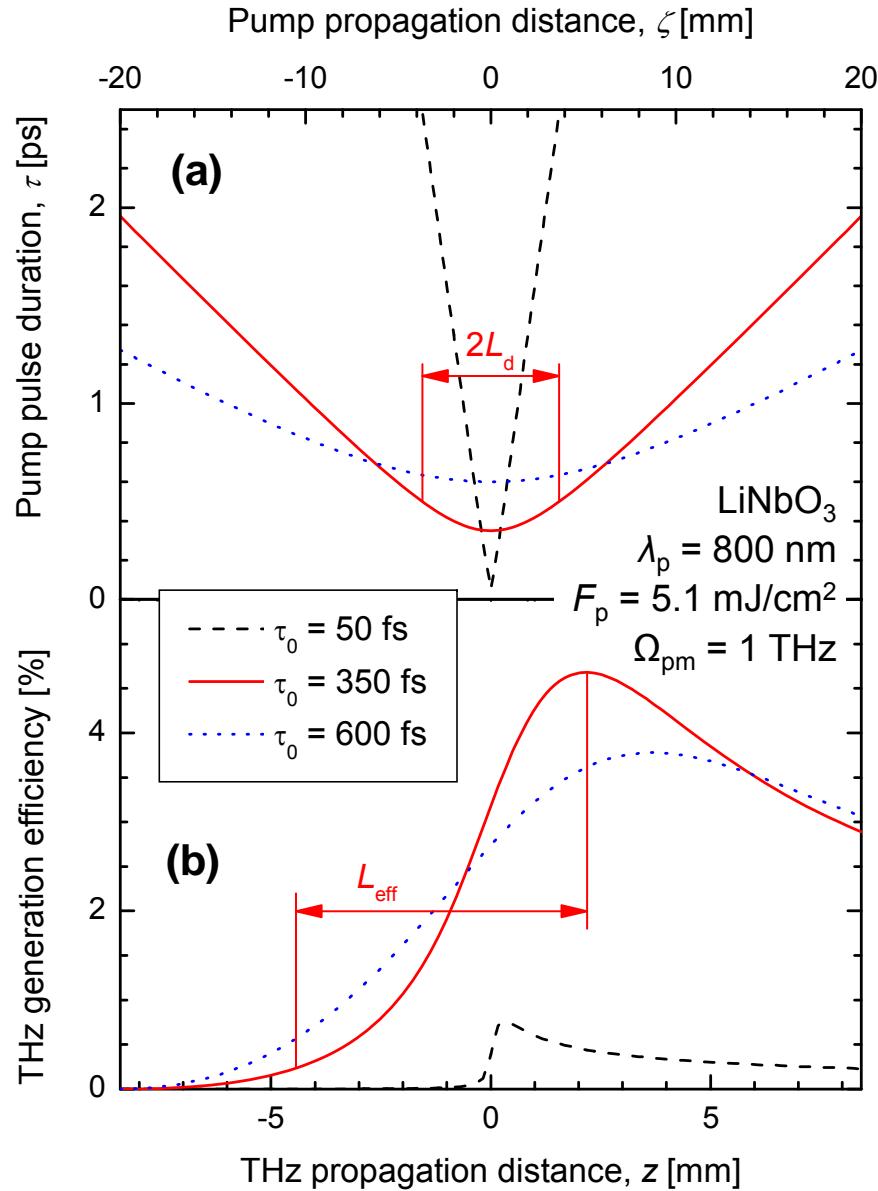
- by increasing the pumped area in optimized setups

Pálfalvi et al., Appl. Phys. Lett., 2008

Fülöp et al., Opt. Express, 2010



Effective Interaction Length



Pulse front tilt:

$$\tan \gamma = -\frac{n}{n_g} \lambda \frac{d\varepsilon}{d\lambda}$$

angular dispersion material dispersion

GVD parameter:

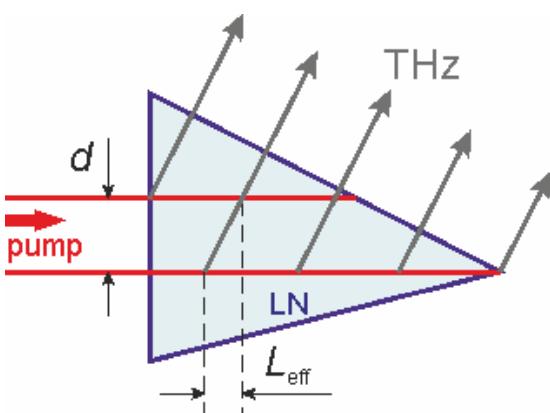
$$D = \frac{d(v_g^{-1})}{d\lambda} = \frac{\lambda}{c} \left[n \left(\frac{d\varepsilon}{d\lambda} \right)^2 - \frac{d^2 n}{d\lambda^2} \right]$$

Martínez et al., JOSAA, 1984

Hebling, Opt. Quantum Electron., 1996

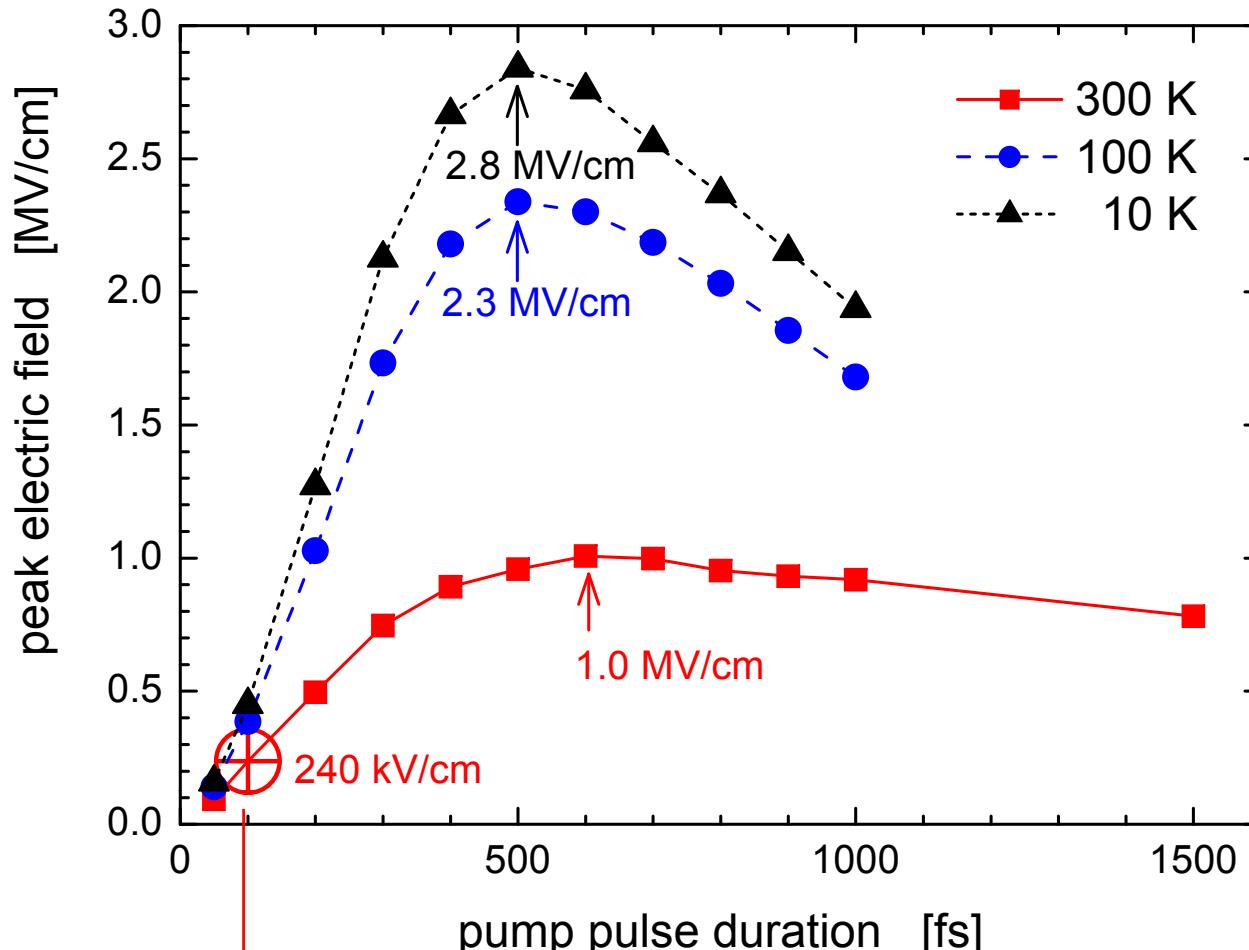
Fülöp et al., Opt. Express, 2010

Effective Interaction Length

Limiting effect	Possible solution
Change of pump pulse duration inside the medium	<ul style="list-style-type: none">▪ Use longer Fourier-limited pump pulses▪ Use materials requiring smaller pulse-front tilt
<p>Absorption at THz frequencies</p> <ul style="list-style-type: none">▪ Absorption coefficient α▪ Multi-photon absorption (MPA) of the pump	<ul style="list-style-type: none">▪ Cool the crystal to reduce α▪ Use longer pump wavelength to suppress low-order MPA
Walk-off  <p>Walk-off</p>	<ul style="list-style-type: none">▪ Use materials requiring smaller pulse-front tilt▪ Use large pump beam (and energy):<ul style="list-style-type: none">→ Optimized imaging system→ Contact grating (no imaging)

Optimization of the Pump Pulse Length

Fülöp et al., Opt. Express, 2011



experimental value: 110 kV/cm

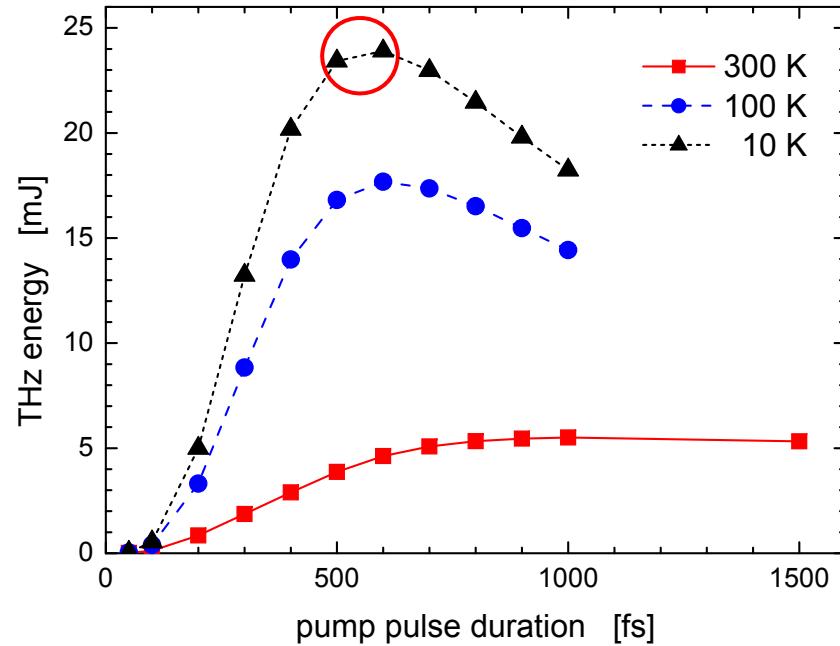
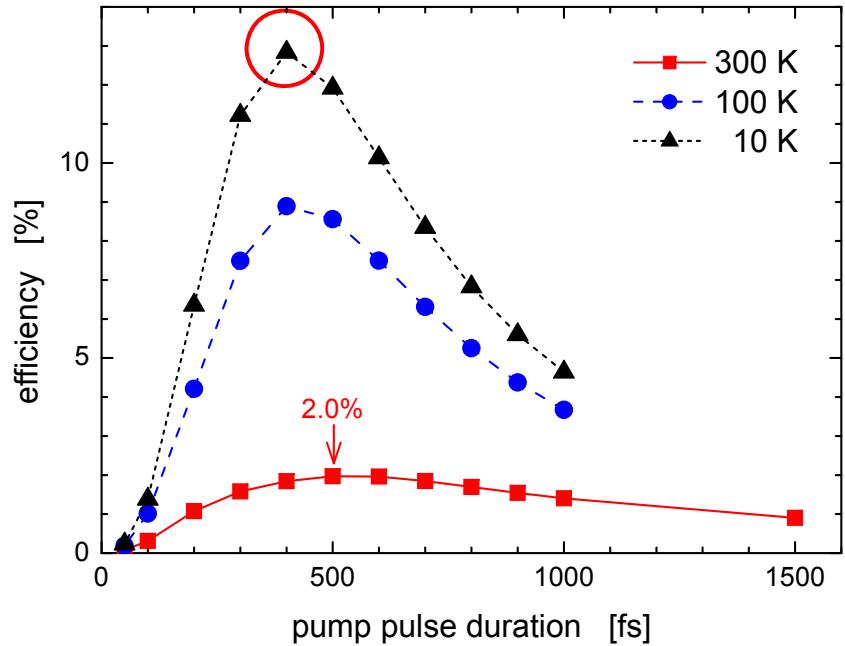
Hoffmann et. al., Phys. Rev. B., 2009

LiNbO_3
 $L \leq 10 \text{ mm}$
 $I_{p, \text{max}} = 40 \text{ GW/cm}^2$
 $\lambda_p = 1064 \text{ nm}$

absorption coefficient of LiNbO_3 :

$T \text{ [K]}$	$\alpha \text{ [1/cm]}$
10	0.35
100	2.1
300	16

Optimization of the Pump Pulse Length



$$\tau_p = 500 \text{ fs}$$

$$E_p = 200 \text{ mJ}$$

$$I_{p, \text{max}} = 40 \text{ GW/cm}^2$$

THz energy $\approx 25 \text{ mJ}$

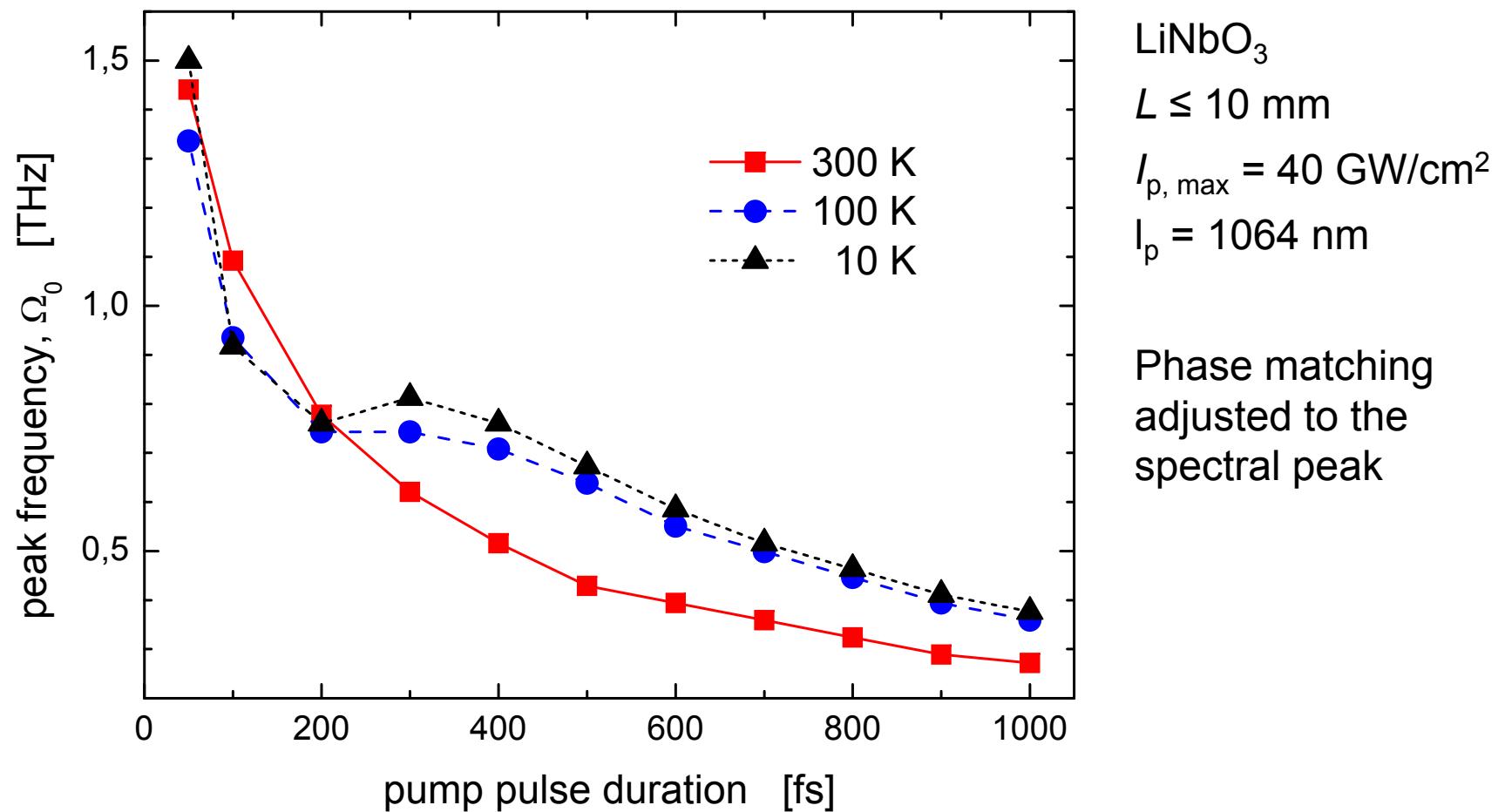
THz field = 2.8 MV/cm (unfocused)

\rightarrow 10 MV/cm level using imaging

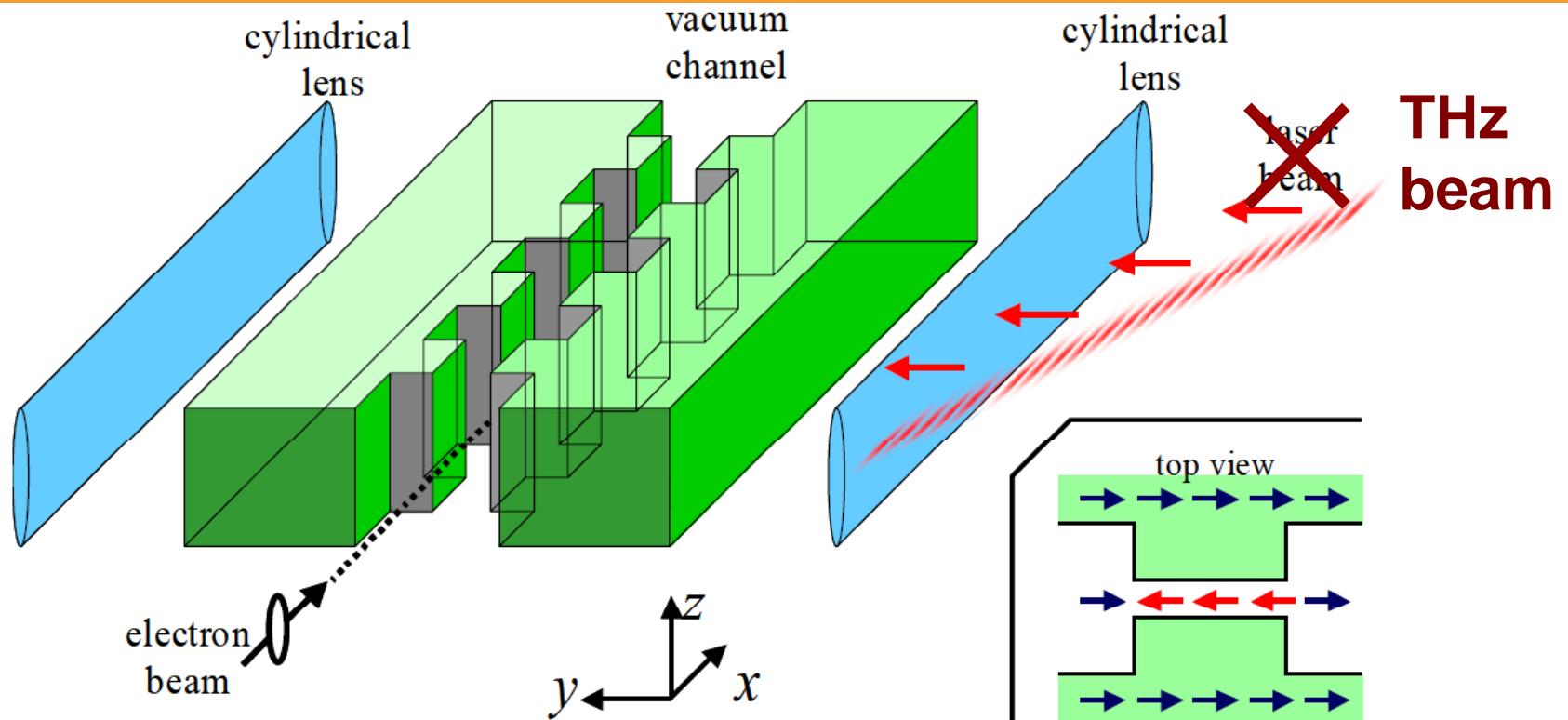
\rightarrow 100 MV/cm level using focusing

Optimization of the Pump Pulse Length

Frequency at the spectral peak



New Application Possibilities for THz Pulses with High Electric Field



- **Acceleration**

Plettner et al., Phys. Rev. Spec. Top. – Accel. and Beams 9, 111301 (2006)

- **Beam deflection, focusing**

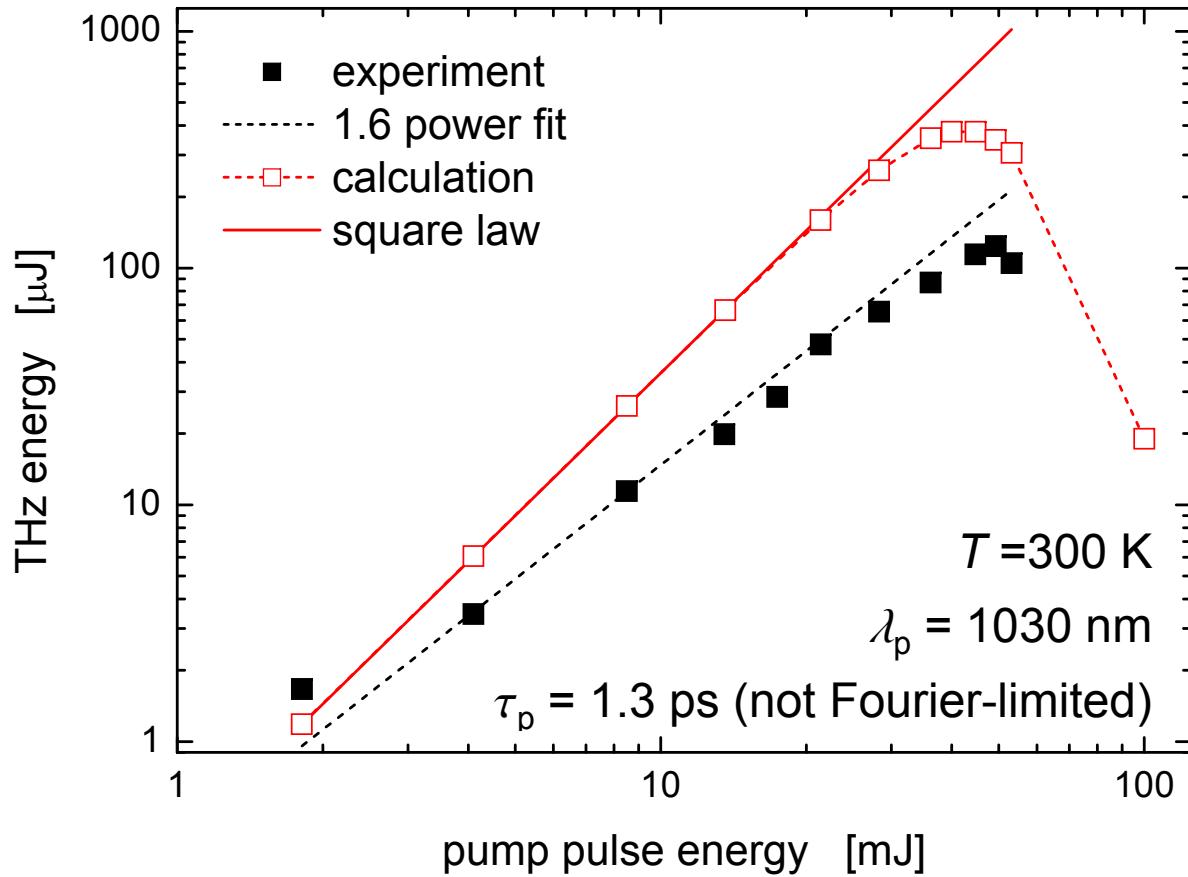
Plettner et al., Phys. Rev. Spec. Top. – Accel. and Beams 12, 101302 (2009)

1 GV/m = 10 MV/cm peak field strength is needed

New Application Possibilities for THz Pulses with High Electric Field

- **Enhancement of HHG**
E. Balogh et al., PRB, 2011
K. Kovács et al., PRL, 2012
- **Longitudinal compression of electron bunches**
→ **single-cycle MIR...XUV pulse generation**
Hebling et al., arXiv:1109.6852
Hebling et al., presentation on Monday
- **Electron undulation**
Hebling et al., arXiv:1109.6852
- **Proton acceleration**
(40 → 100 MeV requires 30 mJ THz energy)
→ **hadron therapy**
Pálfalvi et al., in preparation

Towards mJ Level THz Pulses: Experiment



In collaboration with
S. Klingebiel, F. Krausz, S.
Karsch
MPQ, Garching

Further possibilities:

- Optimal pump duration
- Cooling the LiNbO₃
- Contact grating



Comparison with earlier results:

Stepanov et. al., Appl. Phys. B, 2010:

$$E_{\text{THz}} = 50 \mu\text{J}$$

$$\eta = 0.05\%$$

Fülöp et al., Opt. Lett. 2012:

$$125 \mu\text{J}$$

$$0.25\%$$

$\times 2.5$

$\times 5$

THz Beam Profiles

Contact grating

- No limit for lateral size
- No imaging optics

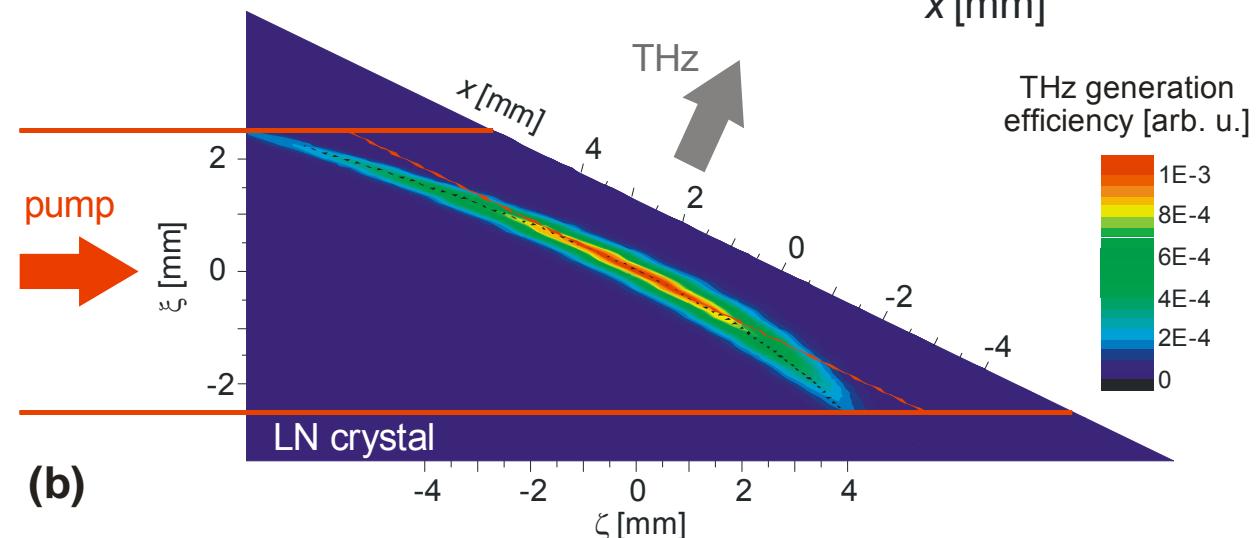
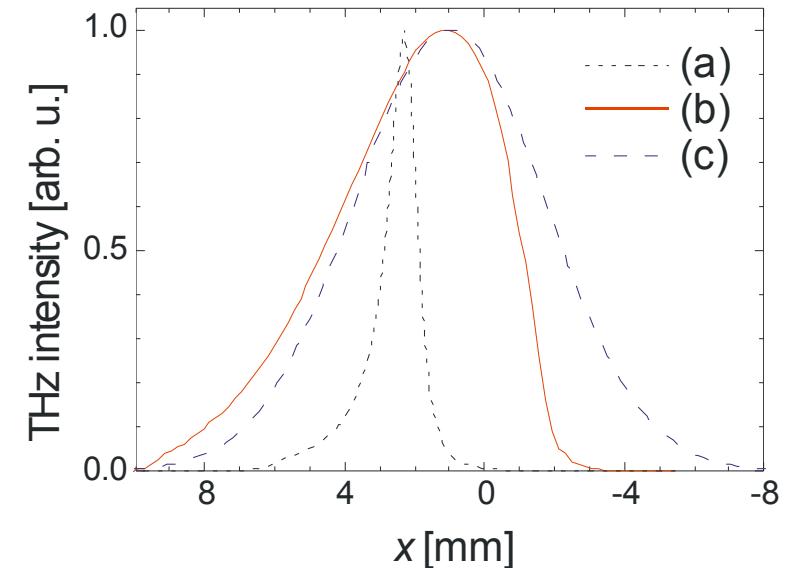
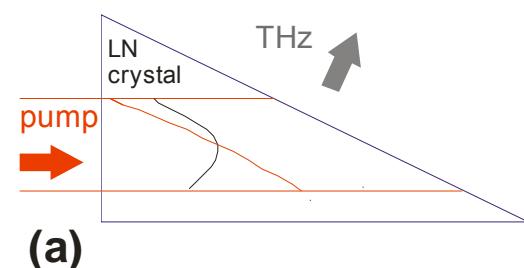
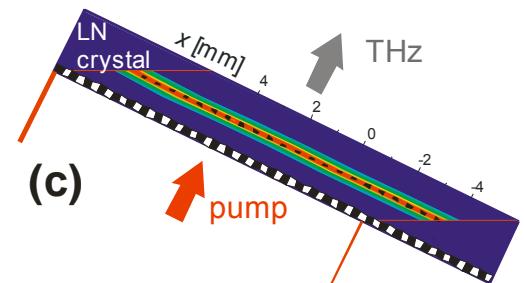
Pálfalvi et al., APL, 2008
Ollmann et al., APB,
submitted

Non-optimized

Optimized

- Grating image is tangential to pulse front
- Longer focal length lens

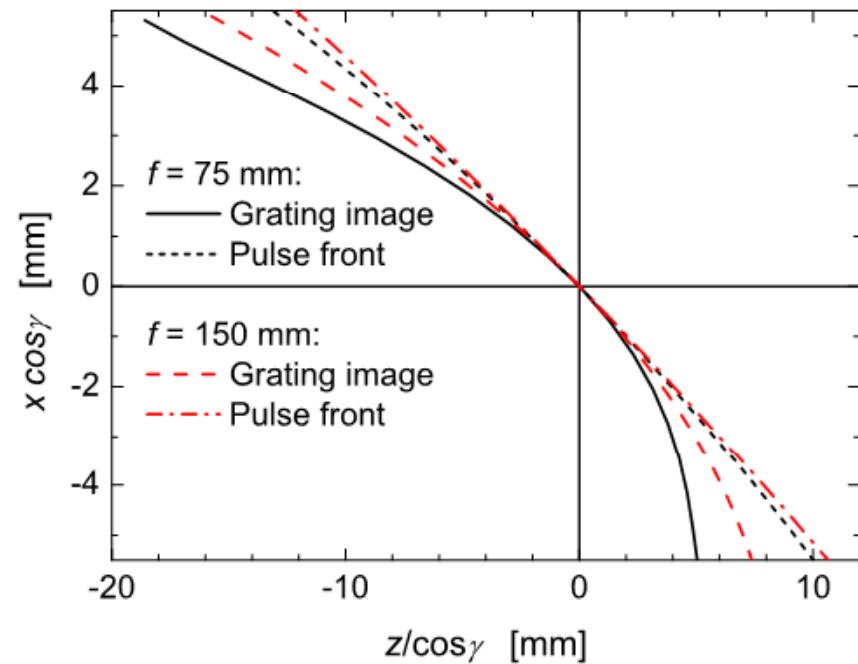
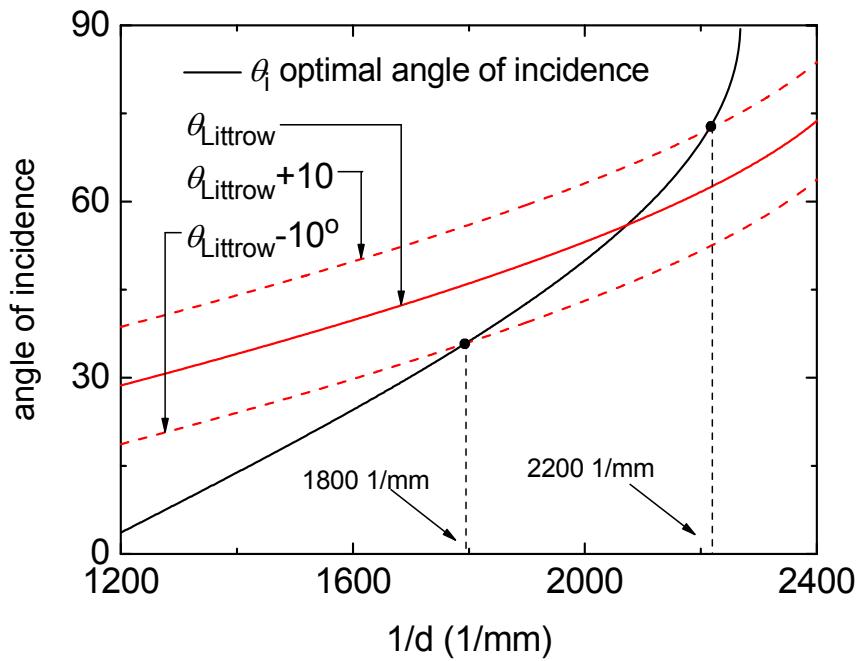
Fülöp et al.,
Opt. Express, 2010



Optimizing the TPFP Setup Containing Imaging

$\text{LiNbO}_3, \lambda_p = 800 \text{ nm}$

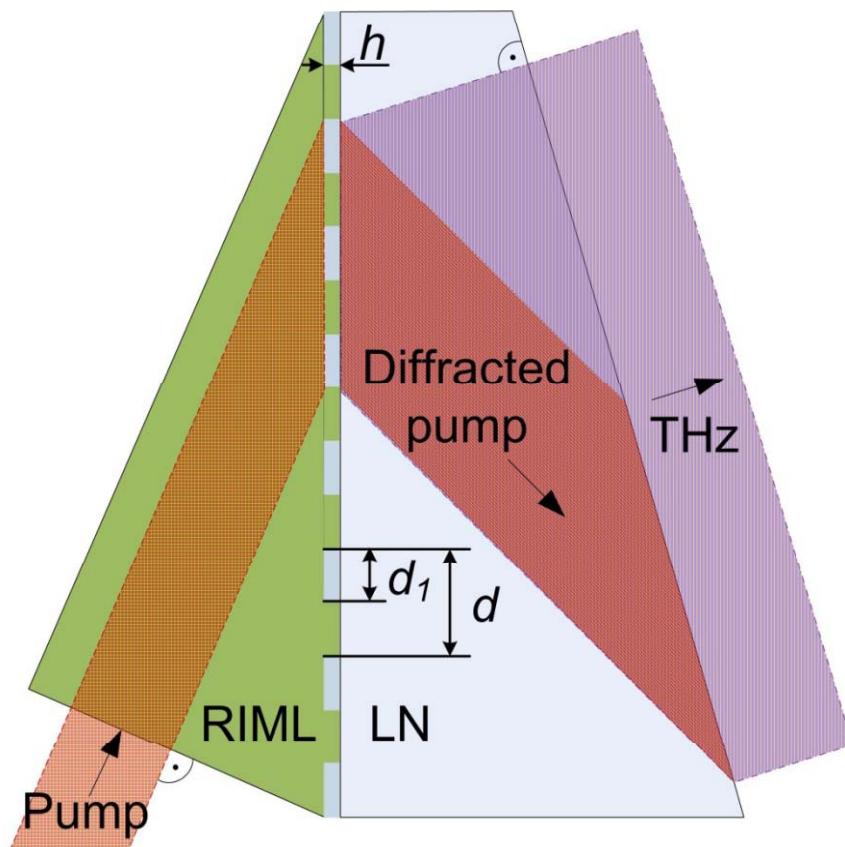
Fülöp et al., Opt. Express, 2010



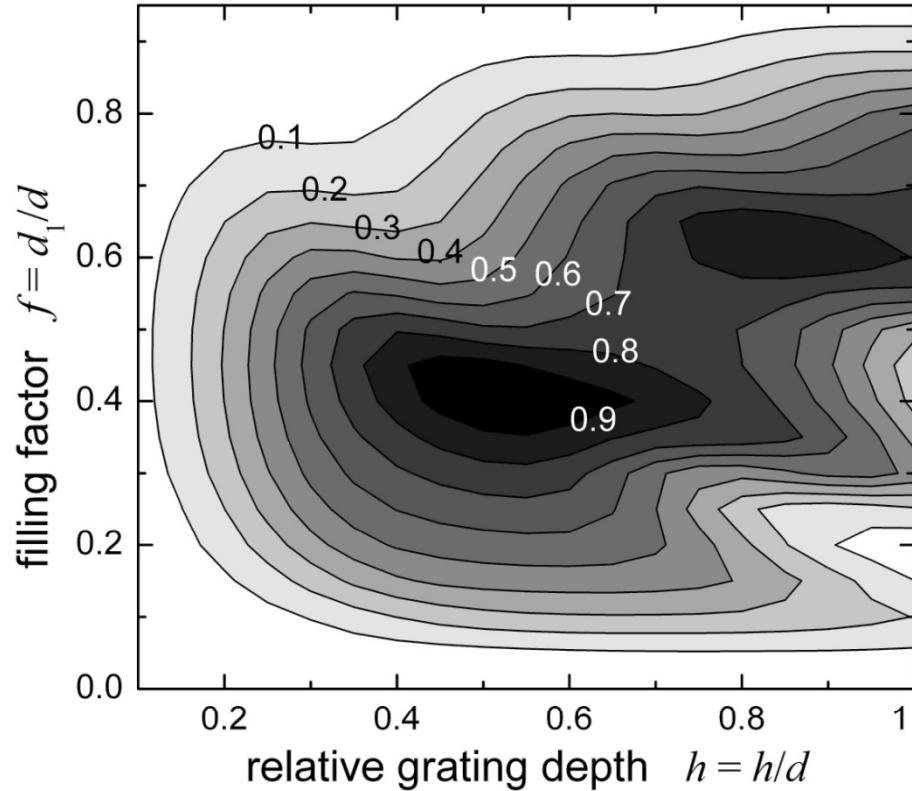
1 MV/cm field and 0.1% efficiency reached by applying our above results
Hirori et al., Appl. Phys. Lett., 2011

Design of Contact Grating on LiNbO₃

- Contact grating for THz generation proposed: Pálfalvi et al., APL, 2008
- Index matching by glass: Nagashima et al., Japan J. Appl. Phys., 2010
- Refractive index matching liquid (RIML): Ollmann et al., APB, submitted

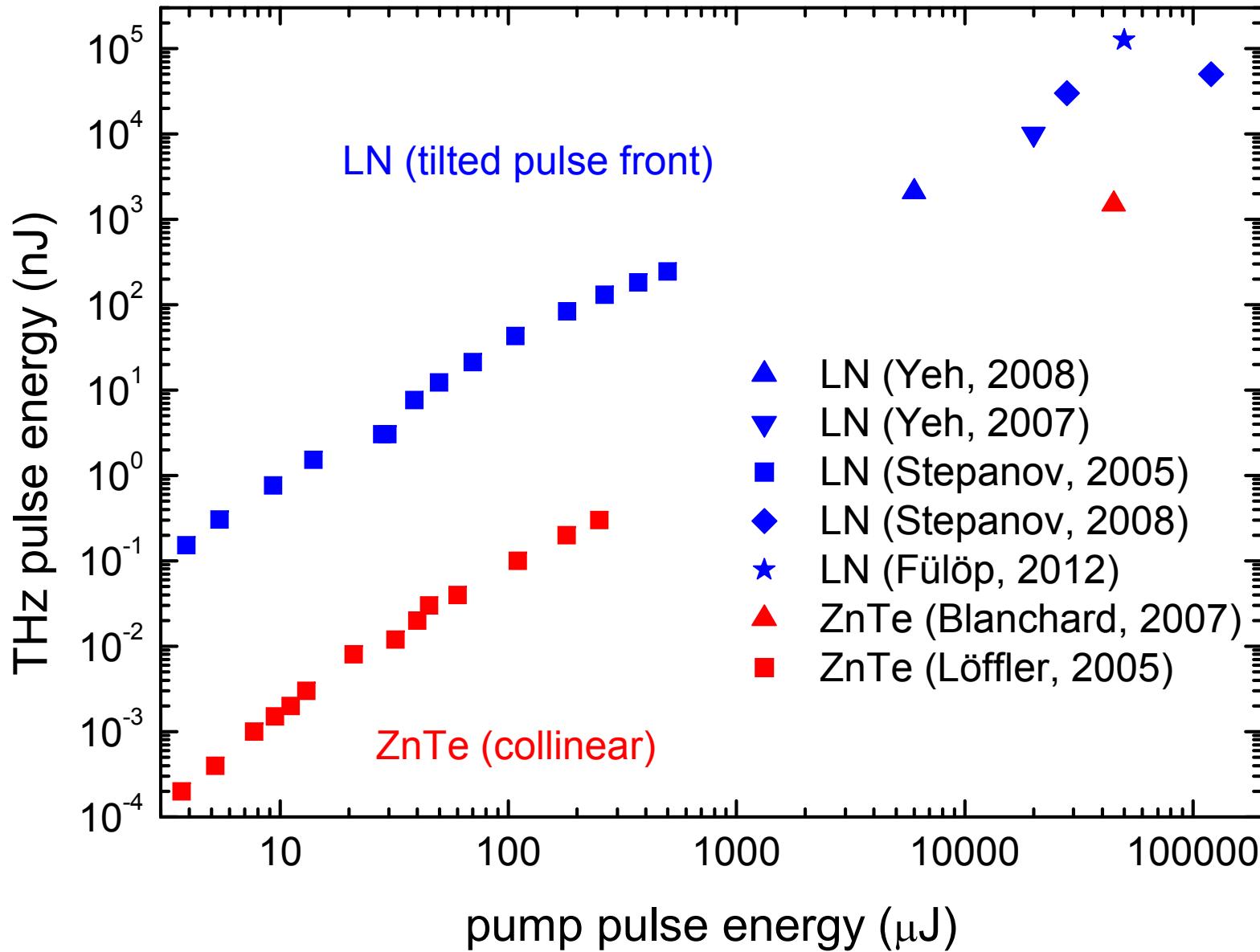


Diffraction efficiency for order -1



RIML for BK7, $d = 350$ nm pitch grating

THz Energy vs. Pump Energy



Reconsidering Semiconductors for THz Generation

Material	$\lambda_p = 800 \text{ nm}$		$\lambda_p = 1064 \text{ nm}$		$\lambda_p = 1560 \text{ nm}$	
	MPA	γ	MPA	γ	MPA	γ
ZnTe	2PA	collinear	2PA	22.4°	3PA	28.6°
GaSe	2PA	16.5°	2PA	25.9°	3PA	30.2°
LiNbO_3	3PA	62.7°	4PA	63.4°	5PA	63.8°

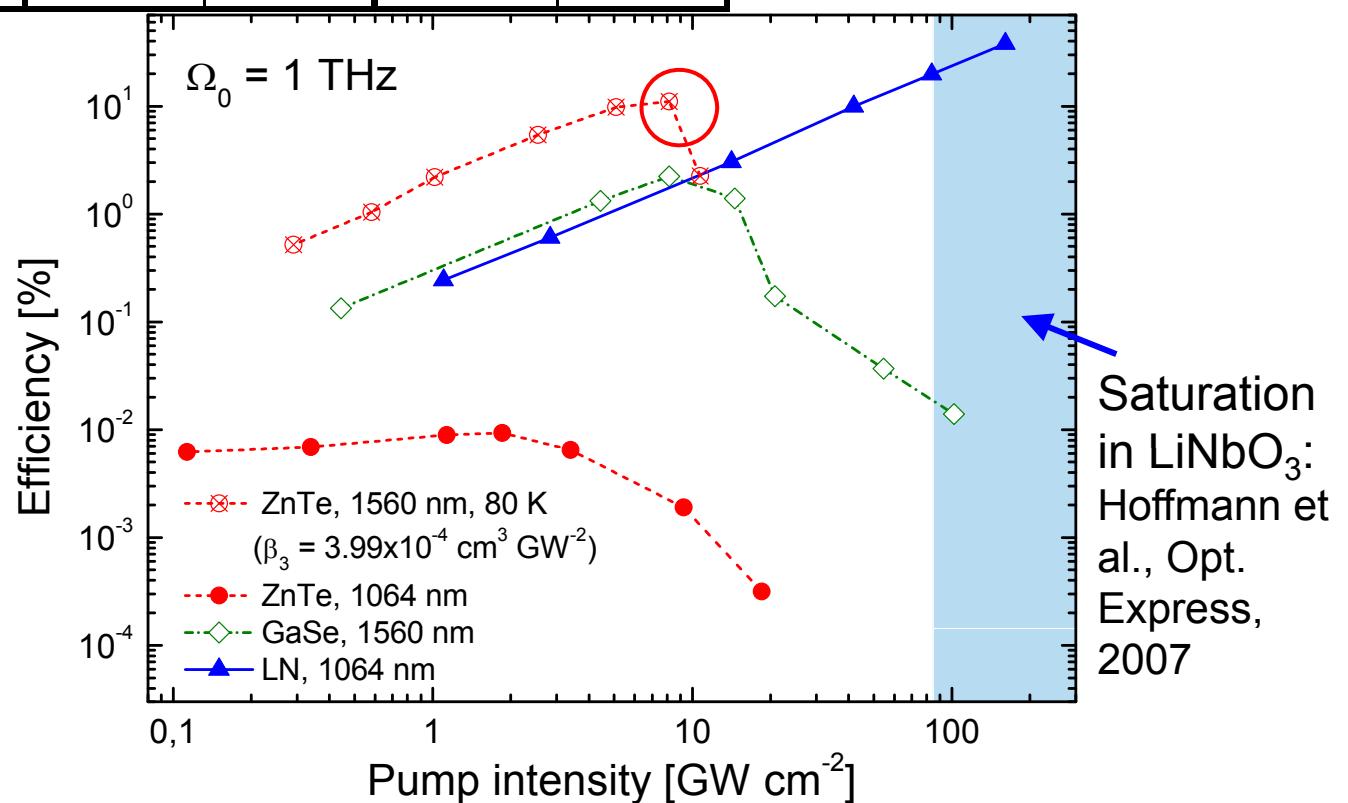
MPA: lowest-order multi-photon pump absorption

γ : pulse-front tilt angle

Fülöp et al.,
Opt. Express, 2010

Advantages:

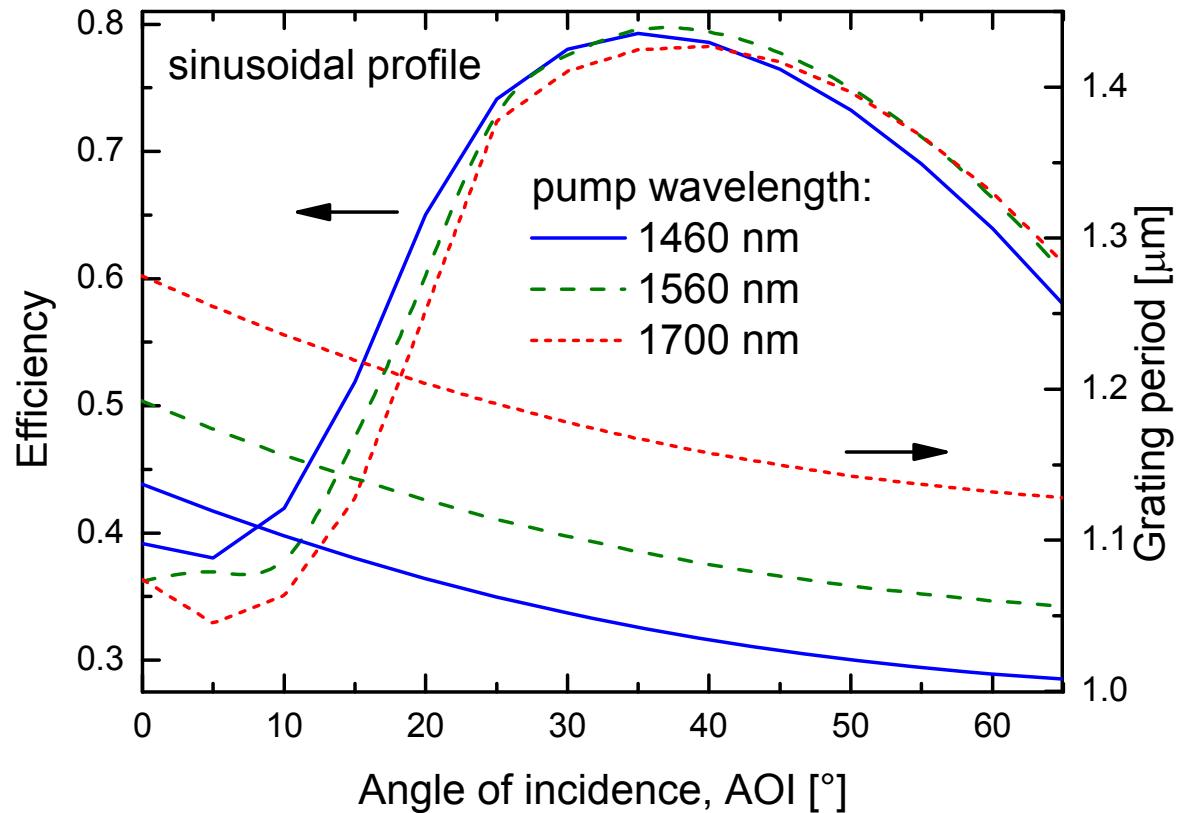
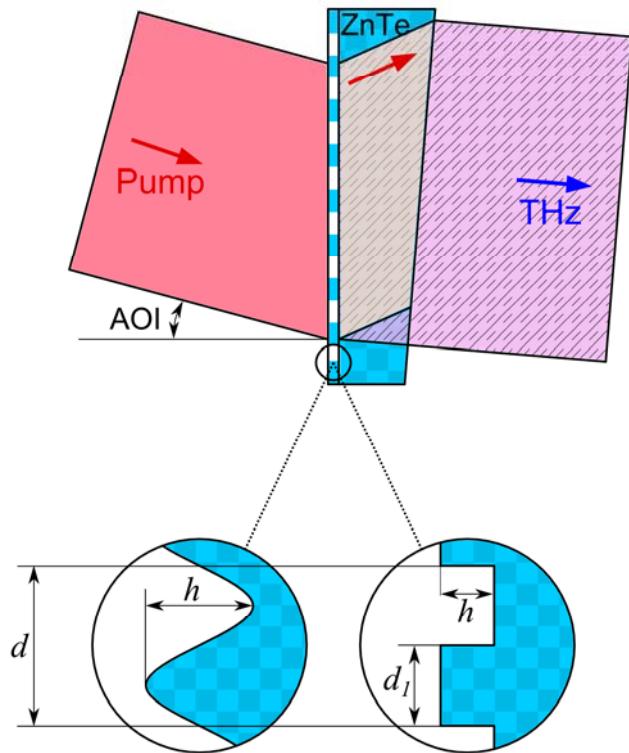
- Pump spot diameter can be increased
- Smaller tilt angle, resulting in longer effective length



Saturation in LiNbO_3 :
Hoffmann et al., Opt. Express, 2007

Design of Contact Grating on ZnTe

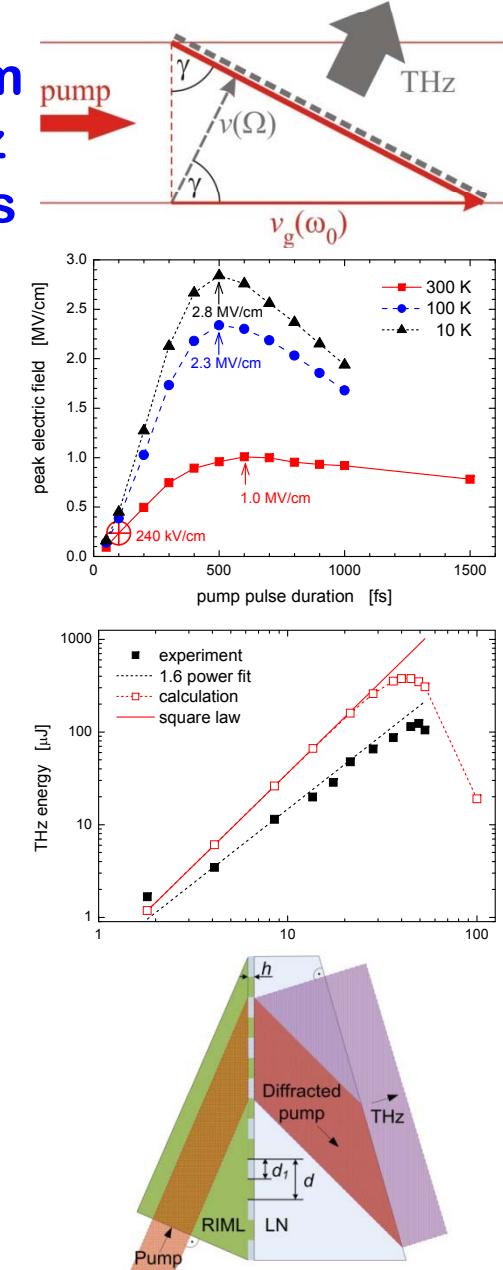
Ollmann et al., in preparation



- Pump: 1.5 μm wavelength, 5 cm beam diameter
- THz energy = 2.2 mJ
 - THz intensity = 630 GW/cm² (focused)
 - THz field ≈ 20 MV/cm (focused)

Summary

- Single-cycle THz pulse generation with 100 MV/cm field and ~10 mJ energy is feasible around ~1 THz frequency by OR pumped by efficient DPSS lasers
- Optimization of the TPFP technique
 - pump pulse duration: 500 fs optimal for LN
 - low crystal temperature
 - optimal crystal length
 - contact grating setup for LN and ZnTe (extension of beam size)
- Preliminary experimental results:
125 μ J energy, 0.25% efficiency (non optimised!)
- New application possibilities:
 - nonlinear THz spectroscopy
 - manipulation of electrons and ions



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